

2SC2898

Silicon NPN Triple Diffused

HITACHI

ADE-208-888 (Z)

1st. Edition

Sep. 2000

Application

High voltage, high speed and high power switching

Outline

勝特力材料 886-3-5753170
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勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

TO-220AB



1. Base
2. Collector (Flange)
3. Emitter

Absolute Maximum Ratings (Ta = 25°C)

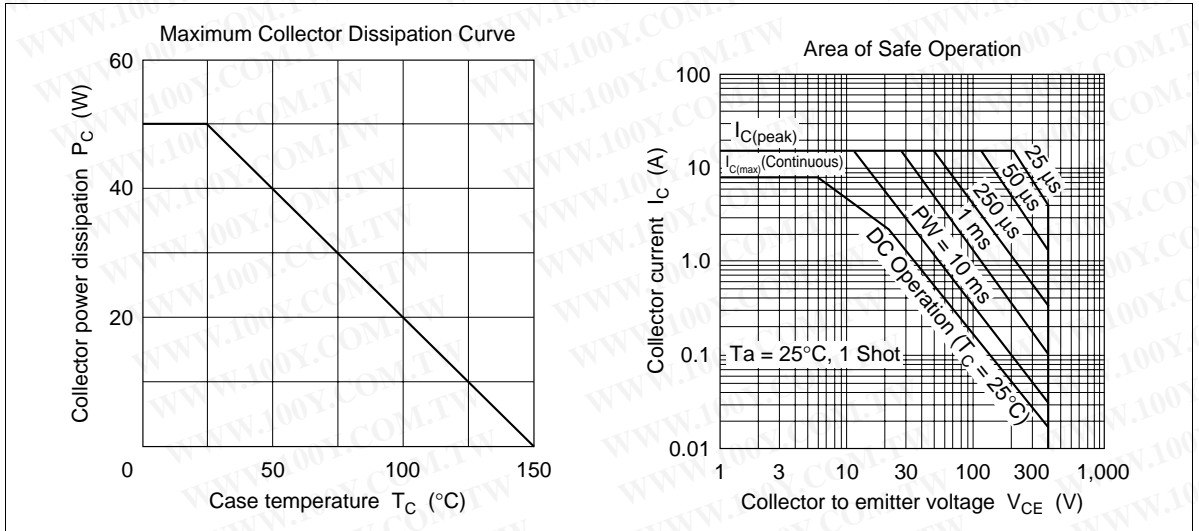
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	500	V
Collector to emitter voltage	V_{CEO}	400	V
Emitter to base voltage	V_{EBO}	7	V
Collector current	I_C	8	A
Collector peak current	$I_{C(peak)}$	16	A
Base current	I_B	4	A
Collector power dissipation	P_C^{*1}	50	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

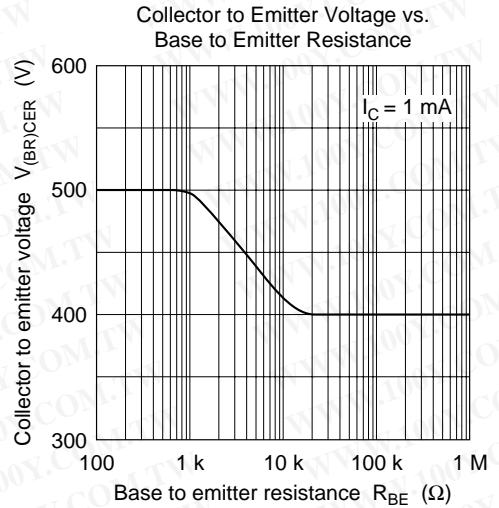
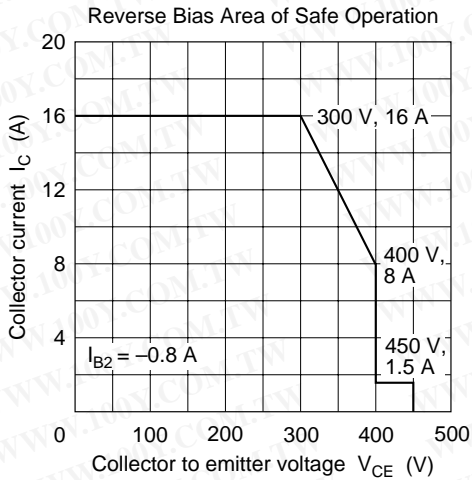
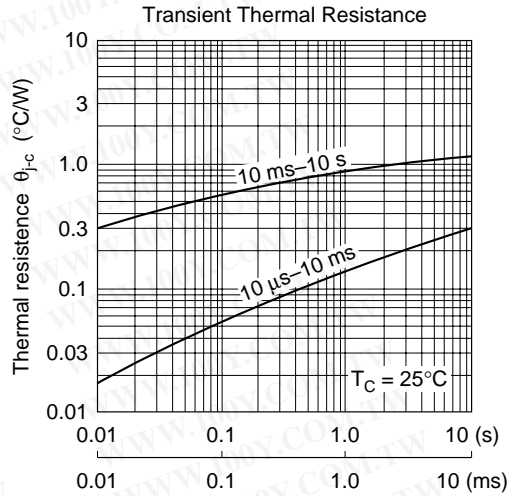
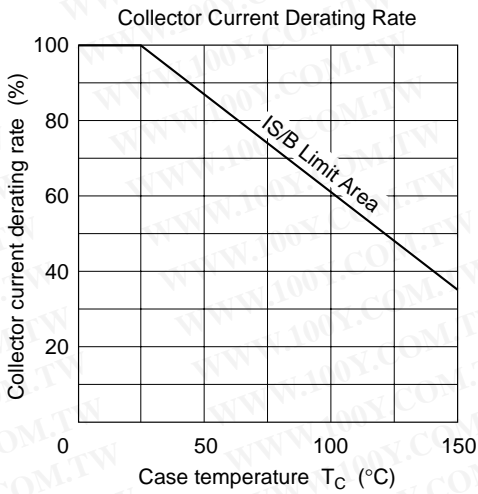
Note: 1. Value at T_c = 25°C.

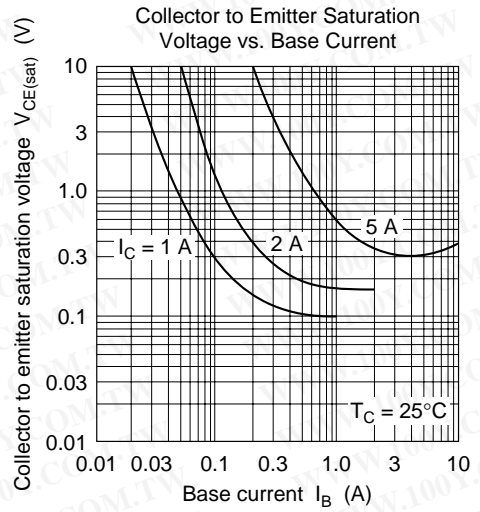
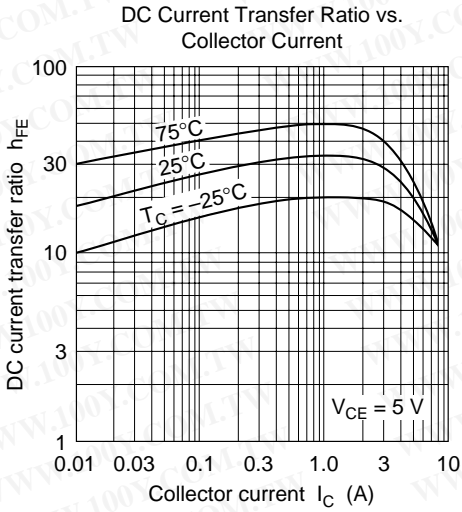
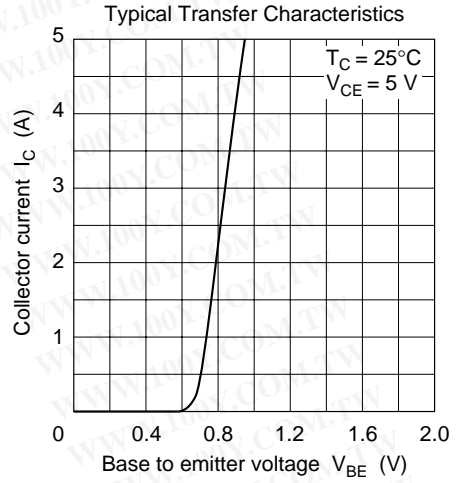
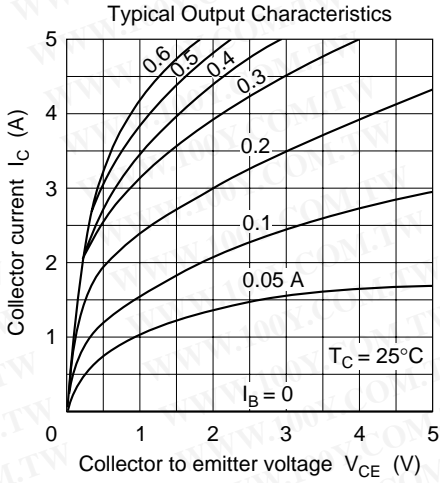
Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter sustain voltage	$V_{CEO(sus)}$	400	—	—	V	$I_C = 0.2\text{ A}$, $R_{BE} = \infty$, $L = 100\text{ mH}$
Collector to emitter sustain voltage	$V_{CEX(sus)}$	400	—	—	V	$I_C = 8\text{ A}$, $I_{B1} = 1.6\text{ A}$, $I_{B2} = -0.8\text{ A}$, $V_{BE} = -5\text{ V}$, $L = 180\text{ }\mu\text{H}$, Clamped
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	—	—	V	$I_E = 10\text{ mA}$, $I_C = 0$
Collector cutoff current	I_{CBO}	—	—	50	μA	$V_{CB} = 400\text{ V}$, $I_E = 0$
	I_{CEO}	—	—	50	μA	$V_{CE} = 350\text{ V}$, $R_{BE} = \infty$
DC current transfer ratio	h_{FE1}	15	—	—		$V_{CE} = 5\text{ V}$, $I_C = 4\text{ A}^{*1}$
	h_{FE2}	7	—	—		$V_{CE} = 5\text{ V}$, $I_C = 8\text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 4\text{ A}$, $I_B = 0.8\text{ A}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	
Turn on time	t_{on}	—	—	0.8	μs	$I_C = 8\text{ A}$, $I_{B1} = -I_{B2} = 1.6\text{ A}$,
Storage time	t_{stg}	—	—	2.0	μs	$V_{CC} \cong 150\text{ V}$
Fall time	t_f	—	—	0.8	μs	

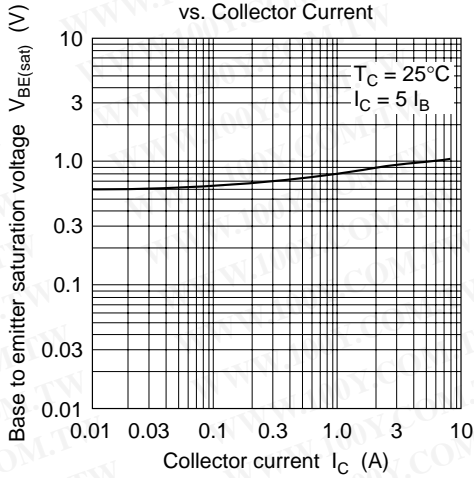
Note: 1. Pulse test



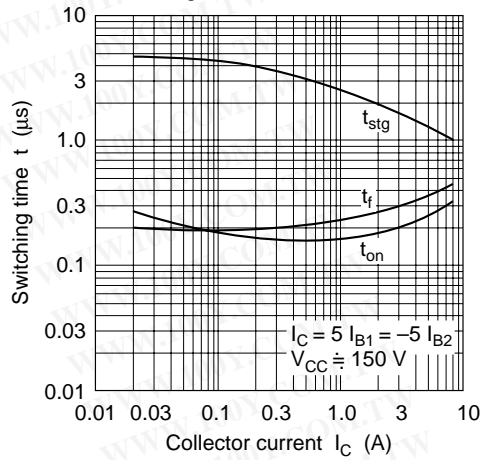




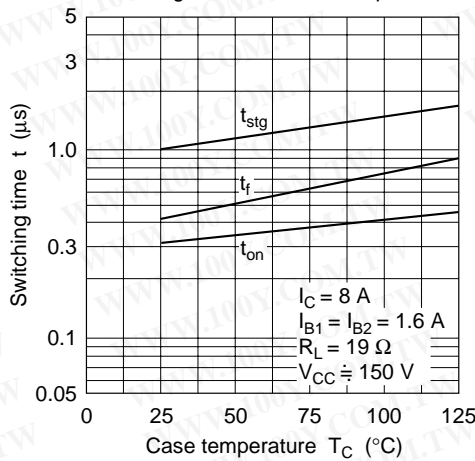
Base to Emitter Saturation Voltage vs. Collector Current



Switching Time vs. Collector Current

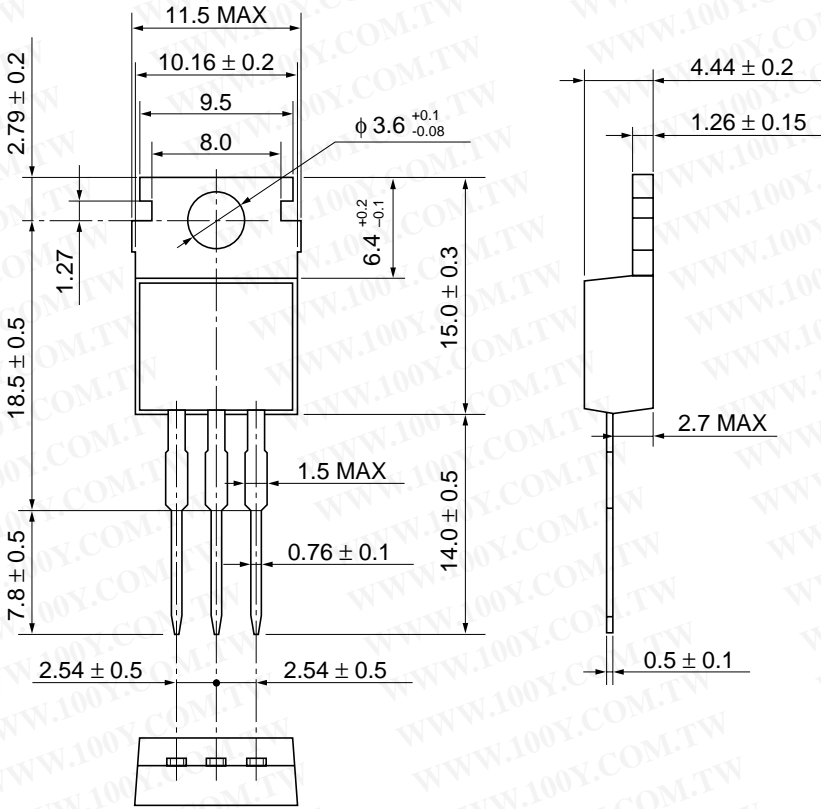


Switching Time vs. Case Temperature



Package Dimensions

Unit: mm



Hitachi Code	TO-220AB
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	1.8 g

Cautions

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